## NSN 5961-00-132-4868

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-132-4868 **Inclosure Material:** Metal **Overall Length:** 0.260 inches **Terminal Length:** 1.500 inches **Overall Diameter:** 0.370 inches **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-5 **Internal Junction Configuration:** Npn **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 breakdown voltage, collector-to-base, emitter open and 8.0 breakdown voltage, emitter-to-base, collector open and 100.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 200.00 milliamperes collector current, dc **Power Rating Per Characteristic:** 4.0 watts small-signal input power, common-collector **Transfer Ratio:** 90.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

Fiig:

No

A110a0